## NSN 5961-01-532-4530

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
Between 0.160 inches and 0.205 inches
Overall Diameter:
Between 0.080 inches and 0.107 inches
End Application:
Nsn 4935-01-136-0233; shop equipment, guided missile system; weapon system: missile, patriot
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
1.00 amperes forward current, average
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0